











#### SN54HC04, SN74HC04

SCLS078G - DECEMBER 1982-REVISED SEPTEMBER 2015

### **SNx4HC04 Hex Inverters**

#### **Features**

- Wide Operating Voltage Range of 2 V to 6 V
- Outputs Can Drive up to 10 LSTTL Loads
- Low Power Consumption, 20-µA Maximum I<sub>CC</sub>
- Typical  $t_{pd} = 8 \text{ ns}$
- ±4-mA Output Drive at 5 V
- Low Input Current of 1 µA Maximum

#### **Applications**

- Cameras
- E-Meters
- **Ethernet Switches**
- Infotainment

#### 3 Description

The SNx4HC04 devices contain six independent inverters. They perform the Boolean function  $Y = \overline{A}$  in positive logic.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	LCCC (20)	8.89 mm × 8.89 mm
SN54HC04	CDIP (14)	19.56 mm × 6.67 mm
	CFP (14)	9.21 mm × 5.97 mm
	SOIC (14)	8.65 mm × 3.91 mm
SN74HC04	PDIP (14)	19.30 mm × 6.35 mm
SN/4HC04	SOP (14)	10.3 mm × 5.3 mm
	TSSOP (14)	5.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### **Logic Diagram (Positive Logic)**





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#### 4 Revision History

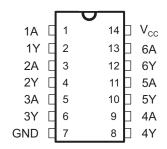
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

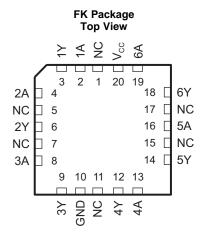
# Changes from Revision F (August 2013) to Revision G Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ESD warning added. Changes from Revision E (October 2010) to Revision F Page Removed Ordering Information table.



#### 5 Pin Configuration and Functions

J, W, D, DB, N, NS, or PW Packages 14-Pin SOIC, CDIP, CFP, PDIP, TSSOP, SOP Top View





NC - No internal connection

#### **Pin Functions**

PIN				
NAME	SOIC, CDIP, CFP, SSOP, PDIP, TSSOP	LCCC	I/O	DESCRIPTION
1A	1	2	I	Input 1A
1Y	2	3	0	Output 1Y
2A	3	4	I	Input 2A
2Y	4	6	0	Output 2Y
3A	5	8	I	Input 3A
3Y	6	9	0	Output 3Y
GND	7	10	_	Ground Pin
4Y	8	12	0	Output 4Y
4A	9	13	I	Input 4A
5Y	10	14	0	Output 5Y
5A	11	16	I	Input 6A
6Y	12	18	0	Output 6Y
6A	13	19	I	Input 6A
VCC	14	20	_	Power Pin
NC	_	1,5,7,11,15,17	_	No Connection

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#### 6 Specifications

#### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	V <sub>O</sub> < 0		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature		-60	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 6.2 ESD Ratings

			VALUE	UNIT
V	Floatroatatia diasharas	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
V <sub>(ESD)</sub> Electrostatic discharge		Machine Model	±250	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

#### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SI	SN54HC04		SI	N74HC04		LINUT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5	6	2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			1.5			
$V_{IH}$	V <sub>IH</sub> High-level input voltage	$V_{CC} = 4.5 \text{ V}$	3.15			3.15			V
		$V_{CC} = 6 V$	4.2			4.2			
V <sub>IL</sub> Low-level input voltage		$V_{CC} = 2 V$			0.5			0.5	V
	Low-level input voltage	$V_{CC} = 4.5 \text{ V}$			1.35			1.35	
		$V_{CC} = 6 V$			1.8			1.8	
$V_{I}$	Input voltage		0		$V_{CC}$	0		$V_{CC}$	V
$V_{O}$	Output voltage		0		$V_{CC}$	0		$V_{CC}$	V
		V <sub>CC</sub> = 2 V			1000			1000	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 4.5 V			500			500	ns
		V <sub>CC</sub> = 6 V			400			400	
T <sub>A</sub>	Operating free-air temperature		-55		125	-40		85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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<sup>2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



#### 6.4 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST	TEST CONDITIONS T <sub>A</sub> = 25°C SN54HC04				1C04	SN74F	IC04	LINUT			
PARAMETER	TEST CONDITIONS		V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2 V	1.9	1.998		1.9		1.9			
		$I_{OH} = -20 \mu A$	4.5 V	4.4	4.499		4.4		4.4			
$V_{OH}$	$V_I = V_{IH}$ or $V_{IL}$		6 V	5.9	5.999		5.9		5.9		V	
		$I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84			
		$I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.8		5.2		5.34			
				2 V		0.002	0.1		0.1		0.1	
		$I_{OL} = 20 \mu A$	4.5 V		0.001	0.1		0.1		0.1		
$V_{OL}$	$V_I = V_{IH}$ or $V_{IL}$		6 V		0.001	0.1		0.1		0.1	V	
		$I_{OL} = 4 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33		
		$I_{OL} = 5.2 \text{ mA}$	6 V		0.15	0.26		0.4		0.33		
I <sub>I</sub>	$V_I = V_{CC}$ or 0	•	6 V		±0.1	±100		±1000		±1000	nA	
Icc	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	6 V			2		40		20	μΑ	
C <sub>i</sub>			6 V		3	10		10		10	pF	

#### 6.5 Switching Characteristics

over operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	то	V	T,	λ = 25°C		SN54HC04	SN74	HC04	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	MIN MA	X MIN	MAX	UNIT
			2 V		45	95	12	5	120	
t <sub>pd</sub>	Α	Υ	4.5 V		9	19	2	9	24	ns
			6 V		8	16	2	5	20	
			2 V		38	75	11	0	95	
t <sub>t</sub>		Υ	4.5 V		8	15	2	2	19	ns
ı			6 V		6	13	,	9	16	

#### 6.6 Operating Characteristics

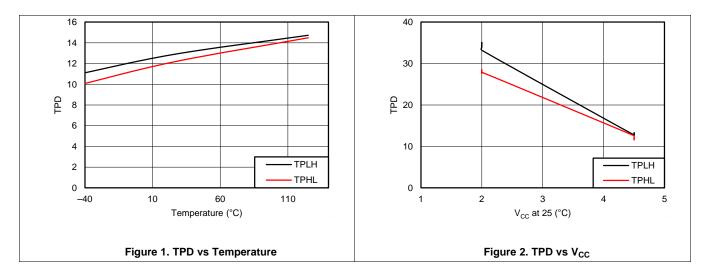
 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance per inverter	No load	20	pF

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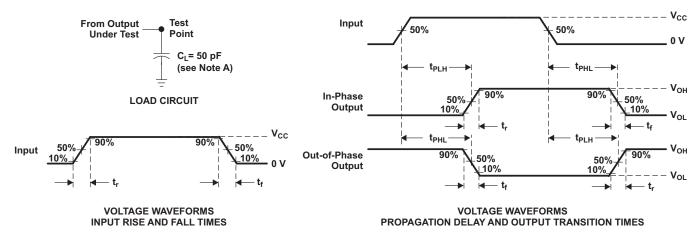


#### 6.7 Typical Characteristics





#### 7 Parameter Measurement Information



- A. C L includes probe and test-fixture capacitance.
- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  MHz,  $Z_O = 50 \Omega$ ,  $t_f = 6$  ns,  $t_f = 6$  ns.
- C. The outputs are measured one at a time with one input transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms



#### 8 Detailed Description

#### 8.1 Overview

The SNX4HC04 device contains six inverter gates. Each inverter gate performs the function of  $Y = \overline{A}$ .

#### 8.2 Functional Block Diagram

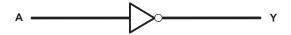


Figure 4. Logic Diagram (Positive Logic)

#### 8.3 Feature Description

The SNx4HC series of devices offer a wide operating voltage range from 2 V to 6 V. The outputs can drive up to 10 LSTTL loads. The SNx4HC04 offers low power consumption of 20  $\mu$ A maximum ICC and typical propagation delays of tpd = 8 ns. At 5 V, the outputs have  $\pm 4$  mA of output drive capability. Inputs have low input current leakage of 1  $\mu$ A maximum.

#### 8.4 Device Functional Modes

Table 1. Function Table (Each Inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

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#### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The SNX4HC04 is a low-drive CMOS device that can be used for a multitude of inverting buffer type functions. The device can produce 4 mA of drive current at 5 V, making it Ideal for driving multiple outputs and good for low-noise applications.

#### 9.2 Typical Application

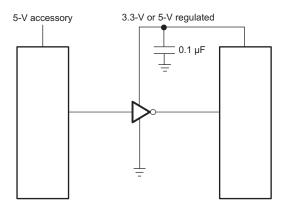


Figure 5. Typical Application Schematic

#### 9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive also creates fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

#### 9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
  - For rise time and fall time specifications, see Δt/ΔV in Recommended Operating Conditions.
  - For specified High and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in Recommended Operating Conditions.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommend Output Conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.

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#### **Typical Application (continued)**

#### 9.2.3 Application Curve

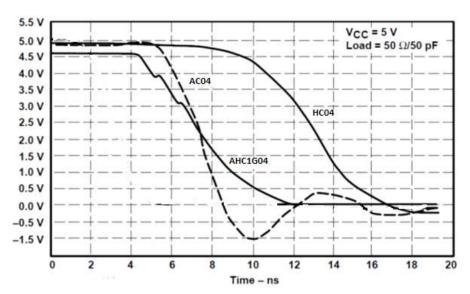


Figure 6. Typical Technology Output Drive Curve



#### 10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in *Recommended Operating Conditions*.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1- $\mu$ F bypass capacitor. If there are multiple  $V_{CC}$  pins, TI recommends a 0.01- $\mu$ F or 0.022- $\mu$ F bypass capacitors for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1  $\mu$ F and 1  $\mu$ F bypass capacitors are commonly used in parallel. For best results, install the bypass capacitor as close to the power pin as possible for best.

#### 11 Layout

#### 11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

#### 11.2 Layout Example

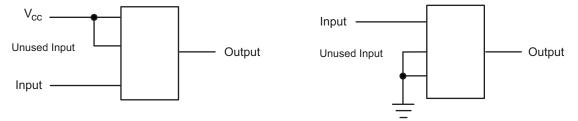


Figure 7. Layout Diagram

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#### 12 Device and Documentation Support

#### 12.1 Related Links

The following table lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	RODUCT FOLDER SAMPLE & BUY TECHNIC DOCUMEN		TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54HC04	Click here	Click here	Click here	Click here	Click here
SN74HC04	Click here	Click here	Click here	Click here	Click here

#### 12.2 Community Resource

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

#### 13 Mechanical, Packaging, and Orderable Information

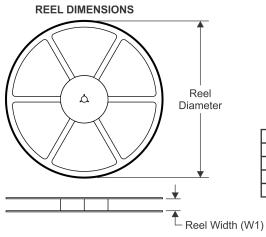
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

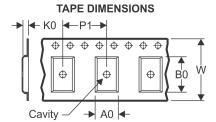
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#### PACKAGE MATERIALS INFORMATION

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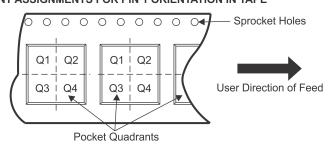
#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

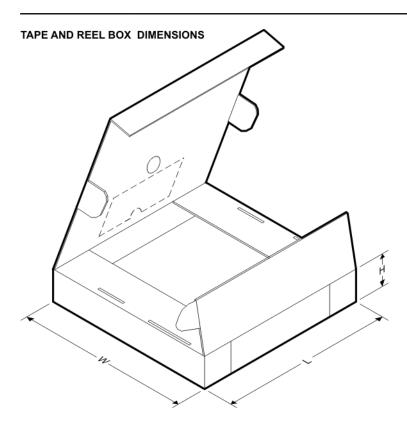
#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

'All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC04DBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74HC04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC04DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC04DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
SN74HC04DRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
SN74HC04DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC04DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC04DT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC04PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC04PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC04PWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC04DBR	SSOP	DB	14	2000	367.0	367.0	38.0
SN74HC04DR	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC04DR	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC04DR	SOIC	D	14	2500	364.0	364.0	27.0
SN74HC04DRG3	SOIC	D	14	2500	364.0	364.0	27.0
SN74HC04DRG4	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC04DRG4	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC04DT	SOIC	D	14	250	367.0	367.0	38.0
SN74HC04PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC04PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74HC04PWRG4	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC04PWT	TSSOP	PW	14	250	367.0	367.0	35.0

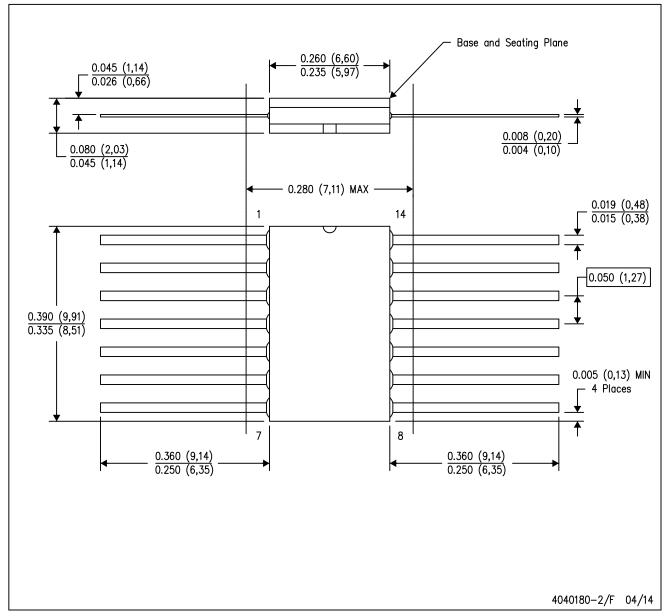
#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# W (R-GDFP-F14)

#### CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



# FK (S-CQCC-N\*\*)

#### LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



## N (R-PDIP-T\*\*)

#### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## D (R-PDSO-G14)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



#### **MECHANICAL DATA**

#### NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



#### DB (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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# HandsOn Technology

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creativity for tomorrow's better living...

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# Welcome to Handsontec Store



LCD+Keyboard Shield



10-Segments LED Bar Display



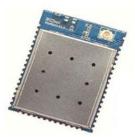
**Ethernet Module** 



Arduino Uno



MicroSD Breakout Board



WiFi Module



20x4 LCD Display Module



Stepper Motor Driver



PWM Motor Speed Controller



Breakout Board & Modules



**Integrated Circuits** 



**Discrete Parts** 



**Assembled Kits** 



Connectors